NSN 5961-01-304-4363

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-304-4363 **Inclosure Material:** Metal **Overall Length:** 1.646 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-48 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.563 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak off-state voltage and 1000.0 repetitive peak reverse voltage and 1200.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes drain current universal and 40.00 amperes forward current, total rms horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 98085-2896-151 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0